Chapter 7 Monitor ROM (MON)

7.1 Introduction

This section describes the monitor ROM (MON) and the monitor mode entry methods. The monitor ROM allows complete testing of the MCU through a single-wire interface with a host computer. This mode is also used for programming and erasing of FLASH memory in the MCU. Monitor mode entry can be achieved without use of the higher test voltage, V_{TST} , as long as vector addresses \$FFFE and \$FFFF are blank, thus reducing the hardware requirements for in-circuit programming.

7.2 Features

Features of the monitor ROM include the following:

- Normal user-mode pin functionality
- One pin dedicated to serial communication between monitor ROM and host computer
- Standard mark/space non-return-to-zero (NRZ) communication with host computer
- Execution of code in RAM or FLASH
- FLASH memory security feature⁽¹⁾
- FLASH memory programming interface
- 959 bytes monitor ROM code size
- Monitor mode entry without high voltage, V_{TST}, if reset vector is blank (\$FFFE and \$FFFF contain \$FF)
- Standard monitor mode entry if high voltage, V_{TST}, is applied to IRQ
- Resident routines for FLASH programming and EEPROM emulation

7.3 Functional Description

The monitor ROM receives and executes commands from a host computer. Figure 7-1 shows a example circuit used to enter monitor mode and communicate with a host computer via a standard RS-232 interface.

Simple monitor commands can access any memory address. In monitor mode, the MCU can execute host-computer code in RAM while most MCU pins retain normal operating mode functions. All communication between the host computer and the MCU is through the PTB0 pin. A level-shifting and multiplexing interface is required between PTB0 and the host computer. PTB0 is used in a wired-OR configuration and requires a pull-up resistor.

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^{1.} No security feature is absolutely secure. However, Motorola's strategy is to make reading or copying the FLASH difficult for unauthorized users.

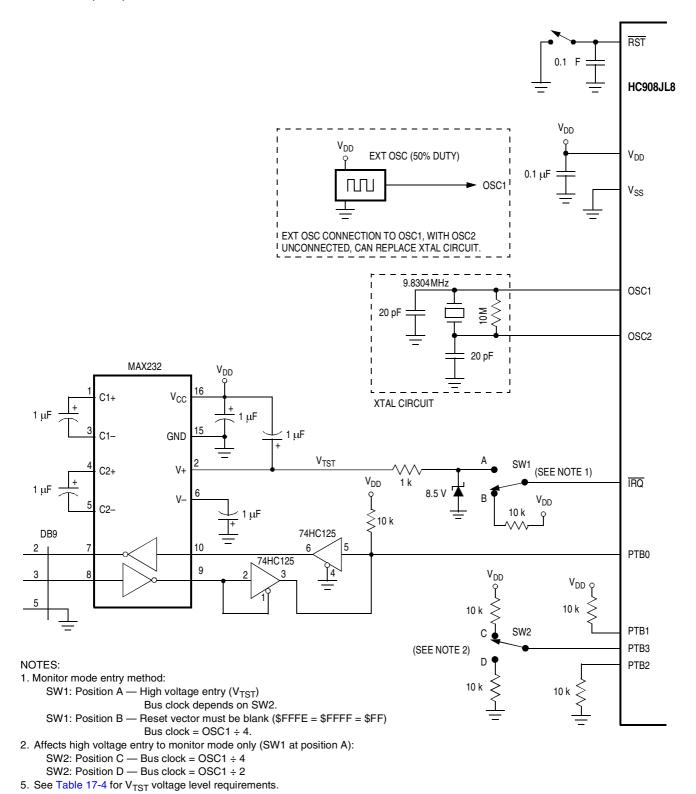


Figure 7-1. Monitor Mode Circuit

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7.3.1 Entering Monitor Mode

Table 7-1 shows the pin conditions for entering monitor mode. As specified in the table, monitor mode may be entered after a POR.

Communication at 9600 baud will be established provided one of the following sets of conditions is met:

- 1. If $\overline{IRQ} = V_{TST}$:
 - Clock on OSC1 is 4.9125MHz
 - PTB3 = low
- 2. If $\overline{IRQ} = V_{TST}$:
 - Clock on OSC1 is 9.8304MHz
 - PTB3 = high
- 3. If \$FFFE and \$FFFF are blank (contain \$FF):
 - Clock on OSC1 is 9.8304MHz
 - $\overline{IRQ} = V_{DD}$

Table 7-1. Monitor Mode Entry Requirements and Options

ĪRQ	\$FFFE and \$FFFF	PTB3	PTB2	PTB1	PTB0	OSC1 Clock ⁽¹⁾	Bus Frequency	Comments	
V _{TST} ⁽²⁾	X	0	0	1	1	4.9152MHz	2.4576MHz	High voltage entry to monitor mode.	
V _{TST} ⁽¹⁾	Х	1	0	1	1	9.8304MHz	2.4576MHz	9600 baud communication on PTB0. COP disabled.	
V _{DD}	BLANK (contain \$FF)	х	х	Х	1	9.8304MHz	2.4576MHz	Blank reset vector (low-voltage) entry to monitor mode. 9600 baud communication on PTB0. COP disabled.	
V _{DD}	NOT BLANK	Х	Х	Х	Х	Х	OSC1 ÷ 4	Enters User mode.	

^{1.} RC oscillator cannot be used for monitor mode; must use either external oscillator or XTAL oscillator circuit.

If V_{TST} is applied to \overline{IRQ} and PTB3 is low upon monitor mode entry (Table 7-1 condition set 1), the bus frequency is a divide-by-two of the clock input to OSC1. If PTB3 is high with V_{TST} applied to \overline{IRQ} upon monitor mode entry (Table 7-1 condition set 2), the bus frequency is a divide-by-four of the clock input to OSC1. Holding the PTB3 pin low when entering monitor mode causes a bypass of a divide-by-two stage at the oscillator *only if* V_{TST} *is applied to* \overline{IRQ} . In this event, the OSCOUT frequency is equal to the 2OSCOUT frequency, and OSC1 input directly generates internal bus clocks. In this case, the OSC1 signal must have a 50% duty cycle at maximum bus frequency.

Entering monitor mode with V_{TST} on \overline{IRQ} , the COP is disabled as long as V_{TST} is applied to either \overline{IRQ} or \overline{RST} . (See Chapter 5 System Integration Module (SIM) for more information on modes of operation.)

If entering monitor mode without high voltage on \overline{IRQ} and reset vector being blank (\$FFFE and \$FFFF) (Table 7-1 condition set 3, where applied voltage is V_{DD}), then all port B pin requirements and conditions,

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^{2.} See Table 17-4 for V_{TST} voltage level requirements.

including the PTB3 frequency divisor selection, are not in effect. This is to reduce circuit requirements when performing in-circuit programming.

Entering monitor mode with the reset vector being blank, the COP is always disabled regardless of the state of IRQ or the RST.

Figure 7-2. shows a simplified diagram of the monitor mode entry when the reset vector is blank and \overline{IRQ} = V_{DD} . An OSC1 frequency of 9.8304MHz is required for a baud rate of 9600.

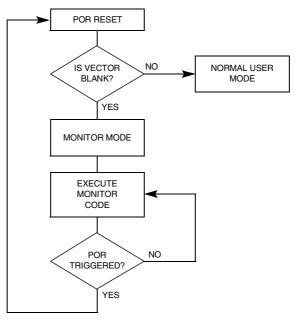


Figure 7-2. Low-Voltage Monitor Mode Entry Flowchart

Enter monitor mode with the pin configuration shown above by pulling \overline{RST} low and then high. The rising edge of \overline{RST} latches monitor mode. Once monitor mode is latched, the values on the specified pins can change.

Once out of reset, the MCU waits for the host to send eight security bytes. (See **7.4 Security**.) After the security bytes, the MCU sends a break signal (10 consecutive logic zeros) to the host, indicating that it is ready to receive a command. The break signal also provides a timing reference to allow the host to determine the necessary baud rate.

In monitor mode, the MCU uses different vectors for reset, SWI, and break interrupt. The alternate vectors are in the \$FE page instead of the \$FF page and allow code execution from the internal monitor firmware instead of user code.

Table 7-2 is a summary of the vector differences between user mode and monitor mode.

Table 7-2	Monitor	· Mode	Vector	Differences
IUDICIE		IVICAC	VCCLO I	

	Functions						
Modes	СОР	Reset Vector High	Reset Vector Low	Break Vector High	Break Vector Low	SWI Vector High	SWI Vector Low
User	Enabled	\$FFFE	\$FFFF	\$FFFC	\$FFFD	\$FFFC	\$FFFD
Monitor	Disabled ⁽¹⁾	\$FEFE	\$FEFF	\$FEFC	\$FEFD	\$FEFC	\$FEFD

Notes:

When the host computer has completed downloading code into the MCU RAM, the host then sends a RUN command, which executes an RTI, which sends control to the address on the stack pointer.

7.3.2 Baud Rate

The communication baud rate is dependant on oscillator frequency. The state of PTB3 also affects baud rate if entry to monitor mode is by $\overline{IRQ} = V_{TST}$. When PTB3 is high, the divide by ratio is 1024. If the PTB3 pin is at logic zero upon entry into monitor mode, the divide by ratio is 512.

Table 7-3. Monitor Baud Rate Selection

Monitor Mode Entry By:	OSC1 Clock Frequency	РТВ3	Baud Rate
	4.9152 MHz	0	9600 bps
$\overline{IRQ} = V_{TST}$	9.8304 MHz	1	9600 bps
	4.9152 MHz	1	4800 bps
Blank reset vector,	9.8304 MHz	Х	9600 bps
$\overline{IRQ} = V_{DD}$	4.9152 MHz	Х	4800 bps

7.3.3 Data Format

Communication with the monitor ROM is in standard non-return-to-zero (NRZ) mark/space data format. (See Figure 7-3 and Figure 7-4.)

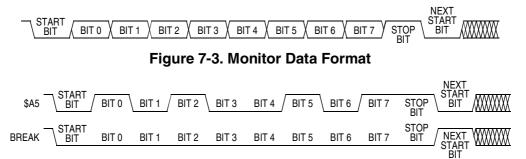


Figure 7-4. Sample Monitor Waveforms

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If the high voltage (V_{TST}) is removed from the IRQ pin or the RST pin, the SIM asserts its COP enable output. The COP is a mask option enabled or disabled by the COPD bit in the configuration register.

The data transmit and receive rate can be anywhere from 4800 baud to 28.8k-baud. Transmit and receive baud rates must be identical.

7.3.4 Echoing

As shown in Figure 7-5, the monitor ROM immediately echoes each received byte back to the PTB0 pin for error checking.

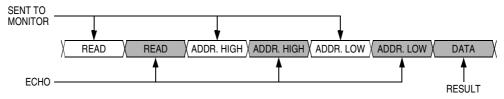


Figure 7-5. Read Transaction

Any result of a command appears after the echo of the last byte of the command.

7.3.5 Break Signal

A start bit followed by nine low bits is a break signal. (See **Figure 7-6**.) When the monitor receives a break signal, it drives the PTB0 pin high for the duration of two bits before echoing the break signal.

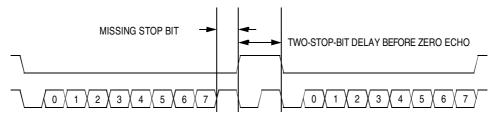


Figure 7-6. Break Transaction

7.3.6 Commands

The monitor ROM uses the following commands:

- READ (read memory)
- WRITE (write memory)
- IREAD (indexed read)
- IWRITE (indexed write)
- READSP (read stack pointer)
- RUN (run user program)

Table 7-4. READ (Read Memory) Command

Description	on Read byte from memory		
Operand	rand Specifies 2-byte address in high byte:low byte order		
Data Returned	Returns contents of specified address		
Opcode	\$4A		
Command Sequence SENT TO MONITOR REA	D X READ ADDR. HIGH ADDR. HIGH ADDR. LOW ADDR. LOW DATA		
ECHO —	RESULT		

Table 7-5. WRITE (Write Memory) Command

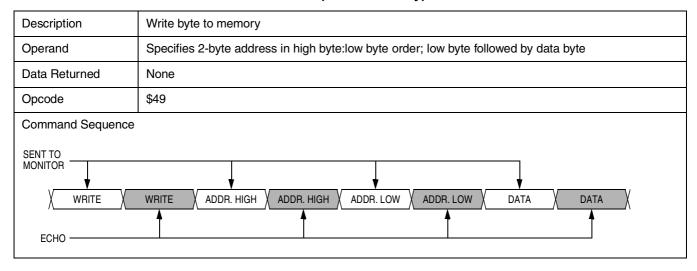
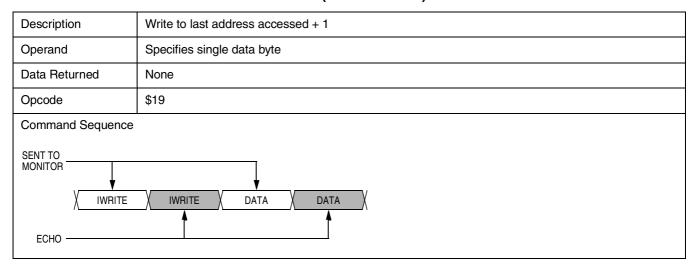


Table 7-6. IREAD (Indexed Read) Command

Description	Read next 2 bytes in memory from last address accessed		
Operand	Specifies 2-byte address in high byte:low byte order		
Data Returned	Returns contents of next two addresses		
Opcode	\$1A		
Command Sequence SENT TO MONITOR VIREAD VIREAD VIREAD VIDATA VI			
ЕСНО —	RESULT		

Table 7-7. IWRITE (Indexed Write) Command



NOTE

A sequence of IREAD or IWRITE commands can sequentially access a block of memory over the full 64-Kbyte memory map.

Table 7-8. READSP (Read Stack Pointer) Command

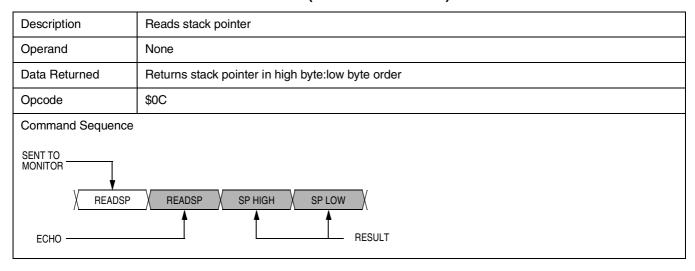


Table 7-9. RUN (Run User Program) Command

Description	Executes RTI instruction		
Operand	None		
Data Returned	None		
Opcode	\$28		
Command Sequence	Command Sequence		
SENT TO MONITOR RUN	RUN		

7.4 Security

A security feature discourages unauthorized reading of FLASH locations while in monitor mode. The host can bypass the security feature at monitor mode entry by sending eight security bytes that match the bytes at locations \$FFF6—\$FFFD. Locations \$FFF6—\$FFFD contain user-defined data.

NOTE

Do not leave locations \$FFF6-\$FFFD blank. For security reasons, program locations \$FFF6-\$FFFD even if they are not used for vectors.

During monitor mode entry, the MCU waits after the power-on reset for the host to send the eight security bytes on pin PTB0. If the received bytes match those at locations \$FFF6—\$FFFD, the host bypasses the security feature and can read all FLASH locations and execute code from FLASH. Security remains bypassed until a power-on reset occurs. If the reset was not a power-on reset, security remains bypassed and security code entry is not required. (See Figure 7-7.)

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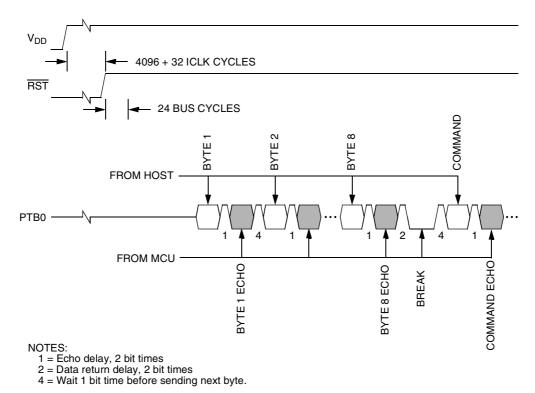


Figure 7-7. Monitor Mode Entry Timing

Upon power-on reset, if the received bytes of the security code do not match the data at locations \$FFF6_\$FFFD, the host fails to bypass the security feature. The MCU remains in monitor mode, but reading a FLASH location returns an invalid value and trying to execute code from FLASH causes an illegal address reset. After receiving the eight security bytes from the host, the MCU transmits a break character, signifying that it is ready to receive a command.

NOTE

The MCU does not transmit a break character until after the host sends the eight security bytes.

To determine whether the security code entered is correct, check to see if bit 6 of RAM address \$60 is set. If it is, then the correct security code has been entered and FLASH can be accessed.

If the security sequence fails, the device should be reset by a power-on reset and brought up in monitor mode to attempt another entry. After failing the security sequence, the FLASH module can also be mass erased by executing an erase routine that was downloaded into internal RAM. The mass erase operation clears the security code locations so that all eight security bytes become \$FF (blank).

7.5 ROM-Resident Routines

Eight routines stored in the monitor ROM area (thus ROM-resident) are provided for FLASH memory manipulation. Six of the eight routines are intended to simplify FLASH program, erase, and load operations. The other two routines are intended to simplify the use of the FLASH memory as EEPROM. Table 7-10 shows a summary of the ROM-resident routines.

Routine Name	Routine Description	Call Address	Stack Used ⁽¹⁾ (bytes)
PRGRNGE	Program a range of locations	\$FC06	15
ERARNGE	Erase a page or the entire array	\$FCBE	9
LDRNGE	Loads data from a range of locations	\$FF30	9
MON_PRGRNGE	Program a range of locations in monitor mode	\$FF28	17
MON_ERARNGE	Erase a page or the entire array in monitor mode	\$FF2C	11
MON_LDRNGE	Loads data from a range of locations in monitor mode	\$FF24	11
EE_WRITE	Emulated EEPROM write. Data size ranges from 2 to 15 bytes at a time.	\$FD3F	24
EE_READ	Emulated EEPROM read. Data size ranges from 2 to 15 bytes at a time.	\$FDD0	16

Table 7-10. Summary of ROM-Resident Routines

The routines are designed to be called as stand-alone subroutines in the user program or monitor mode. The parameters that are passed to a routine are in the form of a contiguous data block, stored in RAM. The index register (H:X) is loaded with the address of the first byte of the data block (acting as a pointer), and the subroutine is called (JSR). Using the start address as a pointer, multiple data blocks can be used, any area of RAM be used. A data block has the control and data bytes in a defined order, as shown in Figure 7-8.

During the software execution, it does not consume any dedicated RAM location, the run-time heap will extend the system stack, all other RAM location will not be affected.

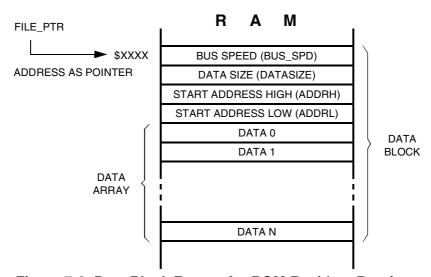


Figure 7-8. Data Block Format for ROM-Resident Routines

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^{1.} The listed stack size excludes the 2 bytes used by the calling instruction, JSR.

The control and data bytes are described below.

- **Bus speed** This one byte indicates the operating bus speed of the MCU. The value of this byte should be equal to 4 times the bus speed, and should not be set to less than 4 (i.e. minimum bus speed is 1 MHz).
- Data size This one byte indicates the number of bytes in the data array that are to be
 manipulated. The maximum data array size is 128. Routines EE_WRITE and EE_READ are
 restricted to manipulate a data array between 2 to 15 bytes. Whereas routines ERARNGE and
 MON_ERARNGE do not manipulate a data array, thus, this data size byte has no meaning.
- **Start address** These two bytes, high byte followed by low byte, indicate the start address of the FLASH memory to be manipulated.
- Data array This data array contains data that are to be manipulated. Data in this array are
 programmed to FLASH memory by the programming routines: PRGRNGE, MON_PRGRNGE,
 EE_WRITE. For the read routines: LDRNGE, MON_LDRNGE, and EE_READ, data is read from
 FLASH and stored in this array.

7.5.1 PRGRNGE

PRGRNGE is used to program a range of FLASH locations with data loaded into the data array.

Routine Name	PRGRNGE
Routine Description	Program a range of locations
Calling Address	\$FC06
Stack Used	15 bytes
Data Block Format	Bus speed (BUS_SPD) Data size (DATASIZE) Start address high (ADDRH) Start address (ADDRL) Data 1 (DATA1) : Data N (DATAN)

Table 7-11. PRGRNGE Routine

The start location of the FLASH to be programmed is specified by the address ADDRH:ADDRL and the number of bytes from this location is specified by DATASIZE. The maximum number of bytes that can be programmed in one routine call is 128 bytes (max. DATASIZE is 128).

ADDRH:ADDRL do not need to be at a page boundary, the routine handles any boundary misalignment during programming. A check to see that all bytes in the specified range are erased is not performed by this routine prior programming. Nor does this routine do a verification after programming, so there is no return confirmation that programming was successful. User must assure that the range specified is first erased.

The coding example below is to program 32 bytes of data starting at FLASH location \$EF00, with a bus speed of 4.9152 MHz. The coding assumes the data block is already loaded in RAM, with the address pointer, FILE_PTR, pointing to the first byte of the data block.

```
ORG
                     RAM
FILE PTR:
BUS SPD
            DS.B
                     1; Indicates 4x bus frequency
DATASIZE
            DS.B
                     1; Data size to be programmed
START_ADDR DS.W DATAARRAY DS.B
                    1; FLASH start address
                    32; Reserved data array
PRGRNGE
             EQU
                     $FC06
                     $EF00
FLASH START EQU
             ORG
                    FLASH
INITIALISATION:
                    BUS SPD
      MOV #20,
                   DATASIZE
            #32,
      MOV
      LDHX #FLASH START
      STHX START ADDR
      RTS
MAIN:
      BSR
            INITIALISATION
      LDHX
             #FILE PTR
       JSR
             PRGRNGE
```

7.5.2 ERARNGE

ERARNGE is used to erase a range of locations in FLASH.

Routine Name ERARNGE

Routine Description Erase a page or the entire array

Calling Address \$FCBE

Stack Used 9 bytes

Data Block Format Bus speed (BUS_SPD)
Data size (DATASIZE)
Starting address (ADDRH)

Table 7-12. ERARNGE Routine

There are two sizes of erase ranges: a page or the entire array. The ERARNGE will erase the page (64 consecutive bytes) in FLASH specified by the address ADDRH:ADDRL. This address can be any address within the page. Calling ERARNGE with ADDRH:ADDRL equal to \$FFFF will erase the entire FLASH array (mass erase). Therefore, care must be taken when calling this routine to prevent an accidental mass erase. To avoid undesirable routine return addresses after a mass erase, the ERARNGE routine should not be called from code executed from FLASH memory. Load the code into an area of RAM before calling the ERARNGE routine.

Starting address (ADDRL)

The ERARNGE routine do not use a data array. The DATASIZE byte is a dummy byte that is also not used.

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The coding example below is to perform a page erase, from \$EF00—\$EF3F. The Initialization subroutine is the same as the coding example for PRGRNGE (see 7.5.1 PRGRNGE).

```
ERARNGE EQU $FCBE
MAIN:

BSR INITIALISATION

:
:
LDHX #FILE_PTR
JSR ERARNGE
```

7.5.3 LDRNGE

LDRNGE is used to load the data array in RAM with data from a range of FLASH locations.

Routine Name	LDRNGE
Routine Description	Loads data from a range of locations
Calling Address	\$FF30
Stack Used	9 bytes
Data Block Format	Bus speed (BUS_SPD) Data size (DATASIZE) Starting address (ADDRH) Starting address (ADDRL) Data 1 : Data N

Table 7-13. LDRNGE Routine

The start location of FLASH from where data is retrieved is specified by the address ADDRH:ADDRL and the number of bytes from this location is specified by DATASIZE. The maximum number of bytes that can be retrieved in one routine call is 128 bytes. The data retrieved from FLASH is loaded into the data array in RAM. Previous data in the data array will be overwritten. User can use this routine to retrieve data from FLASH that was previously programmed.

The coding example below is to retrieve 32 bytes of data starting from \$EF00 in FLASH. The Initialization subroutine is the same as the coding example for PRGRNGE (see 7.5.1 PRGRNGE).

```
LDRNGE EQU $FF30

MAIN:

BSR INITIALIZATION

:
:
LDHX #FILE_PTR
JSR LDRNGE
:
```

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7.5.4 MON_PRGRNGE

In monitor mode, MON_PRGRNGE is used to program a range of FLASH locations with data loaded into the data array.

Routine Name	MON_PRGRNGE
Routine Description	Program a range of locations, in monitor mode
Calling Address	\$FC28
Stack Used	17 bytes
Data Block Format	Bus speed Data size Starting address (high byte) Starting address (low byte) Data 1 : Data N

Table 7-14. MON_PRGRNGE Routine

The MON_PRGRNGE routine is designed to be used in monitor mode. It performs the same function as the PRGRNGE routine (see 7.5.1 PRGRNGE), except that MON_PRGRNGE returns to the main program via an SWI instruction. After a MON_PRGRNGE call, the SWI instruction will return the control back to the monitor code.

7.5.5 MON_ERARNGE

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In monitor mode, ERARNGE is used to erase a range of locations in FLASH.

Routine Name	MON_ERARNGE
Routine Description	Erase a page or the entire array, in monitor mode
Calling Address	\$FF2C
Stack Used	11 bytes
Data Block Format	Bus speed Data size Starting address (high byte) Starting address (low byte)

Table 7-15. MON_ERARNGE Routine

The MON_ERARNGE routine is designed to be used in monitor mode. It performs the same function as the ERARNGE routine (see 7.5.2 ERARNGE), except that MON_ERARNGE returns to the main program via an SWI instruction. After a MON_ERARNGE call, the SWI instruction will return the control back to the monitor code.

7.5.6 MON LDRNGE

In monitor mode, LDRNGE is used to load the data array in RAM with data from a range of FLASH locations.

Table 7-16. ICP_LDRNGE Routine

Routine Name	MON_LDRNGE
Routine Description	Loads data from a range of locations, in monitor mode
Calling Address	\$FF24
Stack Used	11 bytes
Data Block Format	Bus speed Data size Starting address (high byte) Starting address (low byte) Data 1 : Data N

The MON_LDRNGE routine is designed to be used in monitor mode. It performs the same function as the LDRNGE routine (see 7.5.3 LDRNGE), except that MON_LDRNGE returns to the main program via an SWI instruction. After a MON_LDRNGE call, the SWI instruction will return the control back to the monitor code.

7.5.7 EE_WRITE

EE_WRITE is used to write a set of data from the data array to FLASH.

Table 7-17. EE_WRITE Routine

Routine Name	EE_WRITE
Routine Description	Emulated EEPROM write. Data size ranges from 2 to 15 bytes at a time.
Calling Address	\$FD3F
Stack Used	24 bytes
Data Block Format	Bus speed (BUS_SPD) Data size (DATASIZE) ⁽¹⁾ Starting address (ADDRH) ⁽²⁾ Starting address (ADDRL) ⁽¹⁾ Data 1 : Data N

^{1.} The minimum data size is 2 bytes. The maximum data size is 15 bytes.

The start location of the FLASH to be programmed is specified by the address ADDRH:ADDRL and the number of bytes in the data array is specified by DATASIZE. The minimum number of bytes that can be

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^{2.} The start address must be a page boundary start address: \$xx00, \$xx40, \$xx80, or \$00C0.

programmed in one routine call is 2 bytes, the maximum is 15 bytes. ADDRH:ADDRL must always be the start of boundary address (the page start address: \$XX00, \$XX40, \$XX80, or \$00C0) and DATASIZE must be the same size when accessing the same page.

In some applications, the user may want to repeatedly store and read a set of data from an area of non-volatile memory. This is easily possible when using an EEPROM array. As the write and erase operations can be executed on a byte basis. For FLASH memory, the minimum erase size is the page — 64 bytes per page for MC68HC908JL8. If the data array size is less than the page size, writing and erasing to the same page cannot fully utilize the page. Unused locations in the page will be wasted. The EE_WRITE routine is designed to emulate the properties similar to the EEPROM. Allowing a more efficient use of the FLASH page for data storage.

When the user dedicates a page of FLASH for data storage, and the size of the data array defined, each call of the EE_WRTIE routine will automatically transfer the data in the data array (in RAM) to the next blank block of locations in the FLASH page. Once a page is filled up, the EE_WRITE routine automatically erases the page, and starts to reuse the page again. In the 64-byte page, an 4-byte control block is used by the routine to monitor the utilization of the page. In effect, only 60 bytes are used for data storage. (see Figure 7-9). The page control operations are transparent to the user.

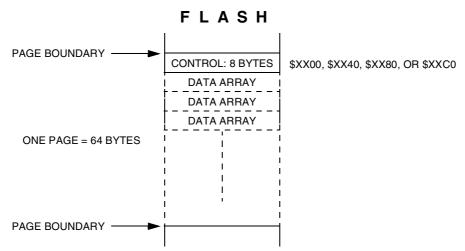


Figure 7-9. EE_WRITE FLASH Memory Usage

When using this routine to store a 3-byte data array, the FLASH page can be programmed 20 times before the an erase is required. In effect, the write/erase endurance is increased by 20 times. When a 15-byte data array is used, the write/erase endurance is increased by 5 times. Due to the FLASH page size limitation, the data array is limited from 2 bytes to 15 bytes.

The coding example below uses the \$EF00-\$EE3F page for data storage. The data array size is 15 bytes, and the bus speed is 4.9152 MHz. The coding assumes the data block is already loaded in RAM, with the address pointer, FILE_PTR, pointing to the first byte of the data block.

```
ORG
                      RAM
FILE PTR:
BUS SPD
             DS.B 1; Indicates 4x bus frequency
DATASIZE
             DS.B
                       1; Data size to be programmed
START_ADDR DS.W 1; FLASH starting address DATAARRAY DS.B 15; Reserved data array
EE WRITE
             EQU
                      $FD3F
FLASH START EQU
                      $EF00
              ORG
                      FLASH
INITIALISATION:
                    BUS_SPD
DATASIZE
       MOV #20,
             #15,
       MOV
       LDHX #FLASH START
       STHX START ADDR
       RTS
MAIN:
       BSR INITIALISATION
       LHDX
              #FILE PTR
       JSR
              EE WRITE
```

NOTE

The EE_WRITE routine is unable to check for incorrect data blocks, such as the FLASH page boundary address and data size. It is the responsibility of the user to ensure the starting address indicated in the data block is at the FLASH page boundary and the data size is 2 to 15. If the FLASH page is already programmed with a data array with a different size, the EE_WRITE call will be ignored.

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7.5.8 EE READ

EE_READ is used to load the data array in RAM with a set of data from FLASH.

Table 7-18. EE_READ Routine

Routine Name	EE_READ
Routine Description	Emulated EEPROM read. Data size ranges from 2 to 15 bytes at a time.
Calling Address	\$FDD0
Stack Used	16 bytes
Data Block Format	Bus speed (BUS_SPD) Data size (DATASIZE) Starting address (ADDRH) ⁽¹⁾ Starting address (ADDRL) ⁽¹⁾ Data 1 : Data N

^{1.} The start address must be a page boundary start address: \$xx00, \$xx40, \$xx80, or \$00C0.

The EE_READ routine reads data stored by the EE_WRITE routine. An EE_READ call will retrieve the last data written to a FLASH page and loaded into the data array in RAM. Same as EE_WRITE, the data size indicated by DATASIZE is 2 to 15, and the start address ADDRH:ADDRL must the FLASH page boundary address.

The coding example below uses the data stored by the EE_WRITE coding example (see 7.5.7 EE_WRITE). It loads the 15-byte data set stored in the \$EF00-\$EE7F page to the data array in RAM. The initialization subroutine is the same as the coding example for EE_WRITE (see 7.5.7 EE_WRITE).

```
EE_READ EQU $FDD0

MAIN:

BSR INITIALIZATION
:
:
LDHX FILE_PTR
JSR EE_READ
:
```

NOTE

The EE_READ routine is unable to check for incorrect data blocks, such as the FLASH page boundary address and data size. It is the responsibility of the user to ensure the starting address indicated in the data block is at the FLASH page boundary and the data size is 2 to 15. If the FLASH page is programmed with a data array with a different size, the EE_READ call will be ignored.

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